

Components and materials

Part 9 August 1979

Piezoelectric quartz devices

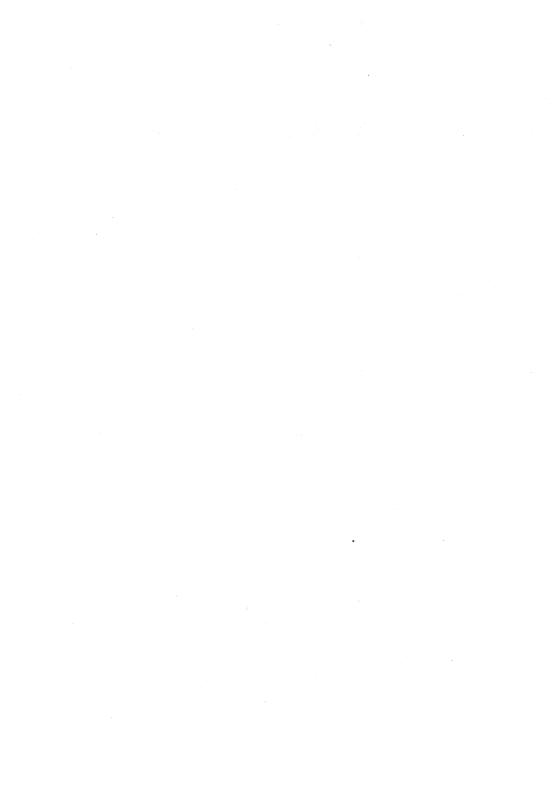
COMPONENTS AND MATERIALS

PART 9 - AUGUST 1979

PIEZOELECTRIC QUARTZ DEVICES

QUARTZ CRYSTAL UNITS GENERAL	. /	4	
---------------------------------	-----	---	--

- QUARTZ CRYSTAL UNITS FOR SPECIAL APPLICATIONS
- QUARTZ CRYSTAL UNITS FOR GENERAL FREQUENCY STABILIZATION
- TEMPERATURE COMPENSATED CRYSTAL OSCILLATORS D



DATA HANDBOOK SYSTEM

Our Data Handbook System is a comprehensive source of information on electronic components, sub-assemblies and materials; it is made up of three series of handbooks each comprising several parts.

ELECTRON TUBES

BLUE

SEMICONDUCTORS AND INTEGRATED CIRCUITS

RED

COMPONENTS AND MATERIALS

GREEN

The several parts contain all pertinent data available at the time of publication, and each is revised and reissued periodically.

Where ratings or specifications differ from those published in the preceding edition they are pointed out by arrows. Where application information is given it is advisory and does not form part of the product specification.

If you need confirmation that the published data about any of our products are the latest available, please contact our representative. He is at your service and will be glad to answer your inquiries.

This information is furnished for guidance, and with no guarantee as to its accuracy or completeness; its publication conveys no licence under any patent or other right, nor does the publisher assume liability for any consequence of its use; specifications and availability of goods mentioned in it are subject to change without notice; it is not to be reproduced in any way, in whole or in part without the written consent of the publisher.

ELECTRON TUBES (BLUE SERIES)

Part 1a	December 1975	ET1a 12-75	Transmitting tubes for communication, tubes for r.f. heating Types PE05/25 to TBW15/25
Part 1b	August 1977	ET1b 08-77	Transmitting tubes for communication, tubes for r.f. heating, amplifier circuit assemblies
Part 2a	November 1977	ET2a 11-77	Microwave tubes Communication magnetrons, magnetrons for microwave heating, klystrons, travelling-wave tubes, diodes, triodes T-R switches
Part 2b	May 1978	ET2b 05-78	Microwave semiconductors and components Gunn, Impatt and noise diodes, mixer and detector diodes, backward diodes, varactor diodes, Gunn oscillators, sub- assemblies, circulators and isolators
Part 3	January 1975	ET3 01-75	Special Quality tubes, miscellaneoùs devices
Part 4	March 1975	ET4 03-75	Receiving tubes
Part 5a	March 1978	ET5a 03-78	Cathode-ray tubes Instrument tubes, monitor and display tubes, C.R. tubes for special applications
Part 5b	December 1978	ET5b 12-78	Camera tubes and accessories, image intensifiers
Part 6	January 1977	ЕТ6 01-77	Products for nuclear technology Channel electron multipliers, neutron tubes, Geiger-Müller tubes
Part 7a	March 1977	ЕТ7а 03-77	Gas-filled tubes Thyratrons, industrial rectifying tubes, ignitrons, high-voltage rectifying tubes
Part 7b	May 1979	ET7b 05-79	Gas-filled tubes Segment indicator tubes, indicator tubes, switching diodes, dry reed contact units
Part 8	July 1979	ЕТ8 07-79	Picture tubes and components Colour TV picture tubes, black and white TV picture tubes, monitor tubes, components for colour television, components for black and white television.
Part 9	March 1978	ET9 03-78	Photomultiplier tubes; phototubes

SEMICONDUCTORS AND INTEGRATED CIRCUITS (RED SERIES)

Part 1a	August 1978	SC1a 08-78	Rectifier diodes, thyristors, triacs Rectifier diodes, voltage regulator diodes (> 1,5 W), transient suppressor diodes, rectifier stacks, thyristors, triacs
Part 1b	May 1977	SC1b 05-77	Diodes Small signal germanium diodes, small signal silicon diodes, special diodes, voltage regulator diodes (< 1,5 W), voltage reference diodes, tuner diodes
Part 2	November 1977	SC2 11-77	Low-frequency and dual transistors*
Part 2	June 1979	SC2 06-79	Low-frequency power transistors
Part 3	January 1978	SC3 01-78	High-frequency, switching and field-effect transistors
Part 4a	December 1978	SC4a 12-78	Transmitting transistors and modules
Part 4b	September 1978	SC4b 09-78	Devices for optoelectronics Photosensitive diodes and transistors, light emitting diodes, photocouplers, infrared sensitive devices, photoconductive devices
Part 4c	July 1978	SC4c 07-78	Discrete semiconductors for hybrid thick and thin-film circuits
Part 5a	November 1978	SC5a 11-76	Professional analogue integrated circuits
Part 5b	March 1977	SC5b 03-77	Consumer integrated circuits Radio-audio, television
Part 6	October 1977	SC6 10-77	Digital integrated circuits LOCMOS HE4000B family
Signetic	s integrated circuits	1978	Bipolar and MOS memories Bipolar and MOS microprocessors Analogue circuits Logic - TTL

^{*} Low-frequency general purpose transistors will be transferred to SC3 later in 1979. The old book SC2 11-77 should be kept until then.

COMPONENTS AND MATERIALS (GREEN SERIES)

Part 1	July 1979	CM1 07-79	Assemblies for industrial use PLC modules, high noise immunity logic FZ/30-series, NORbits 60-series, 61-series, 90-series, input devices, hybrid integrated circuits, peripheral devices
Part 2a	October 1977	CM2a 10-77	Resistors Fixed resistors, variable resistors, voltage dependent resistors (VDR), light dependent resistors (LDR), negative temperature coefficient thermistors (NTC), positive temperature coefficient thermistors (PTC), test switches
Part 2b	February 1978	CM2b 02-78	Capacitors Electrolytic and solid capacitors, film capacitors, ceramic capacitors, variable capacitors
Part 3a	September 1978	CM3a 09-78	FM tuners, television tuners, surface acoustic wave filters
Part 3b	October 1978	СМЗь 10-78	Loudspeakers
Part 4a	November 1978	CM4a 11-78	Soft ferrites Ferrites for radio, audio and television, beads and chokes, Ferroxcube potcores and square cores, Ferroxcube transformer cores
Part 4b	February 1979	CM4b 02-79	Piezoelectric ceramics, permanent magnet materials
Part 6	April 1977	CM6 04-77	Electric motors and accessories Small synchronous motors, stepper motors, miniature direct current motors
Part 7	September 1971	CM7 09-71	Circuit blocks Circuit blocks 100 kHz-series, circuit blocks 1-series, circuit blocks 10-series, circuit blocks for ferrite core memory drive
Part 7a	January 1979	CM7a 01-79	Assemblies Circuit blocks 40-series and CSA70 (L), counter modules 50-series, input/output devices
Part 8	June 1979	CM8 06-79	Variable mains transformers
Part 9	August 1979	CM9 08-79	Piezoelectric quartz devices Quartz crystal units, temperature compensated crystal oscillators
Part 10	April 1978	CM10 04-78	Connectors

QUARTZ CRYSTAL UNITS GENERAL

Α

Survey of types	A2
Introduction	A4
Terms and definitions	A5
Electrical properties and behaviour	Α7
Measuring procedures	A18
Holders	A21
How to specify a quartz crystal unit	A25

SURVEY OF TYPES

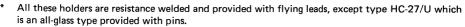
AT-cut quartz crystals for general frequency stabilization.

mode of frequency vibration range MHz		holder			basic
	1	type	housing	connections	- catalogue number
	4 to 10	RW-36 RW-10	resistance welded resistance welded	pins flying leads	4322 148 5 4322 148 6
funda- mental	1,6 to 25	RW-36 HC-6/U HC-27/U	resistance welded solder sealed all-glass	pins pins pins	4322 149 5 4322 152 5 4322 154 5
	4 to 25	HC-26/U HC-29/U RW-43 RW-42	all-glass all-glass resistance welded resistance welded	flying leads pins flying leads pins	4322 155 5 4322 155 6 4322 156 5 4322 156 6
	10 to 61	HC-6/U HC-27/U RW-36	solder sealed all-glass resistance welded	pins pins pins	4322 157 5 4322 159 5 4322 162 5
third overtone	17 to 61	RW-43 RW-42	resistance welded resistance welded	flying leads pins	4322 161 5 4322 161 6
20 t	20 to 61	HC-26/U HC-29/U	all-glass all-glass	flying leads pins	4322 160 5 4322 160 6
fifth	50 to 125	HC-6/U HC-27/U HC-26/U	solder sealed all-glass all-glass	pins pins flying leads	4322 163 5 4322 165 5 4322 166 5
overtone		HC-29/U RW-43 RW-42 RW-36	all-glass resistance welded resistance welded resistance welded	pins flying leads pins pins	4322 166 6 4322 167 5 4322 167 6 4322 168 5



AT-cut quartz crystals for special applications.

frequency MHz	holder *	application	catalogue number
4,000 000	RW-43	tuning	4322 143 04090
4,194 304	RW-43	clocks	4322 143 04070
4,194 812	RW-43	car clocks	4322 143 04060
4,433 619	RW-10	colour television	4322 152 01100
4,433 619	RW-43	colour television	4322 143 04040
4,780 000	RW-43	two-tone dialling	4322 143 04030
5,000 000	RW-43	colour television cameras	8222 298 40760 **
5,120 000	RW-43	car radios	8222 298 40921 **
6,000 000	RW-43	teletext, etc.	4322 143 04100
8,867 238	RW-43	colour television	4322 143 04050
8,867 238	RW-10	colour television	4322 143 03120
10,000 000	HC-27/U	high precision	4322 159 00001



^{**} Development types.



INTRODUCTION

A quartz crystal unit consists of a quartz crystal element with electrodes, mounted in an enclosure with connecting pins or leads.

The quartz crystal element is a vibrating resonant plate which relies upon the piezoelectric effect to couple it to electrical circuits. The intrinsic properties of quartz make it a unique device for accurate and stable frequency control and selection. Although the properties of quartz (T.C., ageing, high Q-factor) are very stable, the ultimate performance of the element is largely dependent on the environment and the associated electrical circuits. We strongly advise that a particular application be discussed with the crystal manufacturer at the earliest stage in any design.

Crystal elements are normally cut in the form of plates or bars. The dimensions of these elements and their orientation with respect to the axes of the crystal give the characteristic of the element. The dimensions are such that the mechanical resonance frequency equals the desired electrical frequency. There are a large number of crystal cuts but the most advantageous orientation is the so-called AT-cut. The frequency range that can be covered herewith is from 1 to 250 MHz. A practical range is from 1,8 to 125 MHz. The crystal element may vibrate in the frequency of a fundamental mode of vibration or in the third, fifth or higher overtone.



TERMS AND DEFINITIONS

in accordance with IEC 122-1

Resonance	frequency	fr
-----------	-----------	----

The lower of the two frequencies of the crystal unit alone, under specified conditions, at which the electrical impedance of the crystal unit is resistive.

Anti-resonance frequency fa

The higher of the two frequencies of a crystal unit alone, under specified conditions, at which the electrical impedance of the crystal unit is resistive.

Load resonance frequency f

One of the two frequencies of a crystal unit in association with a series or with a parallel load capacitance, under specified conditions, at which the electrical impedance of the combination is resistive. This frequency is the lower of the two frequencies when the load capacitance is in series and the higher when it is in parallel (see Fig. 2). For a given value of load capacitance (C_L), these frequencies are identical for all practical purposes and given by:

$$\frac{1}{f} = 2\pi \sqrt{\frac{L_1C_1(C_0 + C_L)}{C_1 + C_0 + C_L}}$$

Nominal frequency fn

The frequency assigned by the specification of the crystal unit.

Working frequency fw

The operational frequency of the crystal unit together with its associated circuits.

Overall tolerance

The maximum permissible deviation of the working frequency from nominal frequency due to a specific cause or a combination of causes.

Adjustment tolerance

The permissible deviation from the nominal frequency at the reference temperature under specified conditions.

Ageing tolerance

The permissible deviation due to time under specified conditions.

Tolerance over the temperature range

The permissible deviation over the temperature range with respect to the frequency at the specified reference temperature.

Tolerance due to level of drive variation

The permissible deviation due to the variation of level of drive.

Operating temperature range	The range of temperatures as measured on the enclo-
	sure over which the crystal unit must function within
	the specified tolerances.

Operable temperature range	The range of temperatures as measured on the enclo-
	sure over which the crystal unit must function though
	not necessarily within the specified tolerances.

Reference temperature	The temperature at which certain crystal measurements are made. For controlled temperature units, the reference temperature is the mid-point of the controlled
	temperature range. For non-controlled temperature
	units, the reference temperature is normally 25 ± 2 °C.

Resonance resistance R	The resistance of the crystal unit alone at the reson-
	ance frequency f _r .

Load resonance resistance
$$R_L$$
 The resistance of the crystal unit in series with a stated external capacitance at the load resonance frequency f_L .

Note: The value of
$$R_{\perp}$$
 is related to the value of R by the following expression:

$$R_L = R \left(1 + \frac{C_0}{C_L}\right)^2$$

A measure of the conditions imposed upon the
crystal unit expressed in terms of power dissipated.

Note: In special cases, the level of drive may be
specified in terms of crystal current or voltage.

The effective external capacitance associated with the crystal unit which determines the load resonance frequency
$$f_L$$
.

Note: Such parameter variation is due to long-term changes in the crystal unit and is usually expressed in fractional parts per period of time.

Level of drive

Unwanted response

Load capacitance C₁

Ageing (long-term parameter variation)

Motional capacitance C₁

Motional inductance L₁

ELECTRICAL PROPERTIES AND BEHAVIOUR

CRYSTAL UNIT EQUIVALENT CIRCUIT

The equivalent circuit, which has the same impedance as the unit in the immediate neighbourhood of resonance, is usually represented by an inductance, capacitance and resistance in series, this series branch being shunted by the capacitance between the terminals of the unit. The parameters of the series branch are usually given by L_1 , C_1 and R_1 . The parallel capacitance is given by C_0 (see Fig. 1).

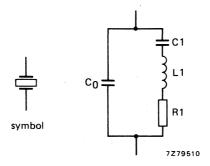


Fig. 1 Crystal unit equivalent circuit.

The parameters of the series branch are termed the "motional parameters" of the crystal unit. The parameter C_0 is termed the "parallel capacitance".

The equivalent circuit has two resonance frequencies at which the electrical impedance is resistive: the "resonance frequency f_{Γ} " and the "anti-resonance frequency f_{α} ". The resistance of the equivalent circuit at the resonance frequency f_{Γ} is termed the "resonance resistance R".

For $R_1 \ll \frac{1}{\omega C_0}$ the following relations hold:

$$f_r = \frac{1}{2\pi\sqrt{L_1C_1}} \tag{1}$$

$$f_a = \frac{1}{2\pi\sqrt{L_1 \frac{C_1 C_0}{C_1 + C_0}}}$$
 (2)

$$R = R_1 \tag{3}$$

QUARTZ CRYSTAL UNITS

LOAD CAPACITANCE AND FREQUENCY PULLING

During manufacture definable limits are set to the accuracy of frequency. In an oscillator, a load capacitance C_L is required to trim the working frequency f_W to the nominal frequency f_{n} . Figure 2 shows the crystal unit equivalent circuit with a load capacitance in series and in parallel. Each combination has two resonance frequencies at which the electrical impedance of the circuit is resistive. The lower of the two frequencies, when the load capacitance is connected in series and the higher, when it is connected in parallel are termed "load resonance frequencies f_L ". At the frequency f_L the resistance of the combination with the load capacitance in series is termed "load resonance resistance R_L ". For $R_1 \ll 1/\omega C_0$:

$$f_{L} = \frac{1}{2\pi \sqrt{\frac{c_{1}(c_{0} + c_{L})}{c_{1} + (c_{0} + c_{L})}}}$$
(4)

$$R_L = R (1 + \frac{C_0}{C_L})^2$$
 * (5)

For a given value of C_L the load resonance frequencies of the series and the parallel combinations are identical.

In practice, however, the parallel combination shown in Fig. 2c rarely occurs in an oscillator. From equation (4) two conspicuous second parameters of vital concern can be derived: the difference between load resonance frequency f_L and resonance frequency f_r , " Δf ", and the relative change in frequency as a function of the change in load capacitance, termed "pulling sensitivity S".

"\\f"

$$\Delta f = f_{L} - f_{r} \tag{6}$$

with f₁ from equation (4)

$$\Delta f = \frac{1}{2} f_r \frac{C_1}{C_0 + C_L} - \frac{\Delta f^2}{2 f_s}$$
 (7)

and to a close approximation

$$\Delta f = \frac{1}{2} f_r \frac{C_1}{C_0 + C_L}$$
 (8)

Equation (8) greatly simplifies calculations and methods of measurement, whilst the error is negligible in nearly all cases.

$$R_{L par} = \frac{1}{R_{1} \cdot \omega_{r}^{2} (C_{0} + C_{L})^{2}}$$

^{*} The resistance of the combination with the load capacitance in parallel is given by

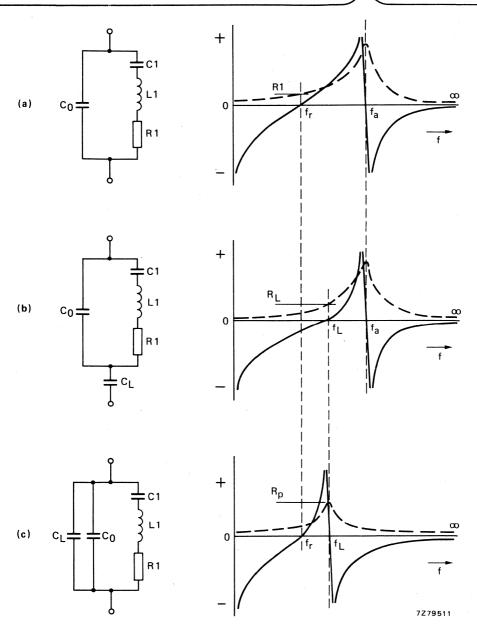


Fig. 2 Resonance, anti-resonance and load resonance frequency.

---- reactance

Pulling sensitivity S

$$S = \frac{1}{f_L} \; (\frac{\delta f}{\delta C_L}) \; _{f \; = \; f_L} = + \frac{1}{f_L} \; . \; \frac{\delta \Delta f}{\delta C_L} \label{eq:spectrum}$$

with Δf from equation (8)

$$S = -\frac{1}{2} f_r \frac{C1}{(C_0 + C_1)^2} \cdot \frac{1}{f_L}$$
 (9)

and to a close approximation

$$S = -\frac{C1}{2(C_0 + C_L)^2}$$
 (10)

Standard values of load capacitance

The standard values of load capacitance for crystal units operating at the fundamental frequency of the mode are:

Note that in some countries 32 pF is still in use, but this value should not be considered as a standard value and its use is deprecated.

In special cases load capacitances of the values 8, 12 and 15 pF may be used for fundamental mode crystal units.

Overtone crystals are often operated at series resonance. Where a load capacitance is used, it should be chosen from the following standard values:

The pulling sensitivity expressed in 10^{-6} /pF is a good measure for the frequency sensitivity as a function of load capacitance variations at the working frequency.

Figure 3 illustrates Δf and the pulling sensitivity S as a function of the load capacitance, for two quartz crystals having different C₁ values. It should be noted that a tolerance of ½ pF on a 20 pF load capacitance may lead to an error of \pm 11.10⁻⁶.

Crystal (a)	Crystal (b)
$f_r = 10000,000 \text{ kHz}$	$f_r = 10000,000\text{kHz}$
$C_0 = 5 pF$	$C_0 = 2 pF$
C ₁ = 28 fF	C ₁ = 5,6 fF
C _L = 20 pF	C _L = 20 pF
f _L = 10 005,600 kHz	f _L = 10 001,273 kHz
$S = -22,4.10^{-6}/pF$	$S = -5.79.10^{-6}/pF$

Specified, or in special cases, measured Δf and S, as given for crystal (a) in Table 1, offer a simple direct guidance.

Table 1

nominal frequency f _n = f _L	10 000,000 kHz		
nominal load capacitance CL	20 pF		
	specified	measured	
Δf	5,600 kHz	5,700 kHz	
pulling sensitivity S	$-22 \pm 2 \times 10^{-6}/pF$	$-22,4 \times 10^{-6}/pF$	



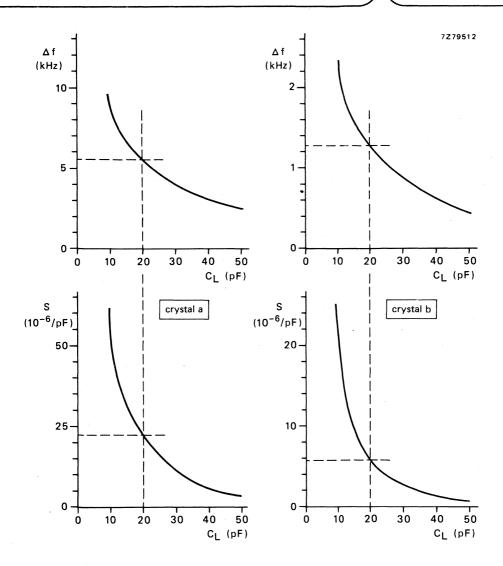


Fig. 3 Δf and pulling sensitivity as a function of the load capacitance. Tolerances on the parameters f_r , C_0 and C_1 are required for calculating the " Δf " and the "pullability at f_n ".

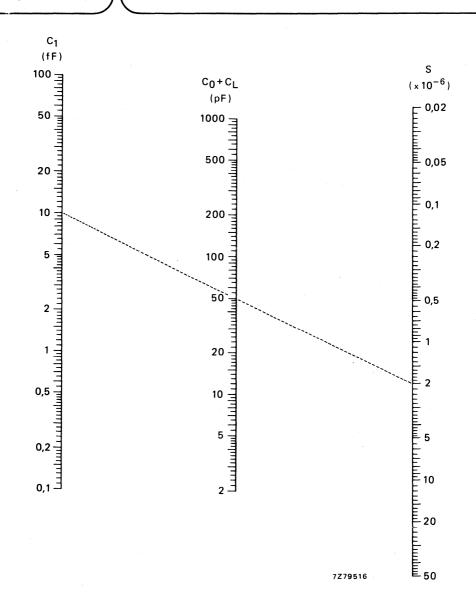


Fig. 4 Nomogram enabling the determination of the pulling sensitivity S.



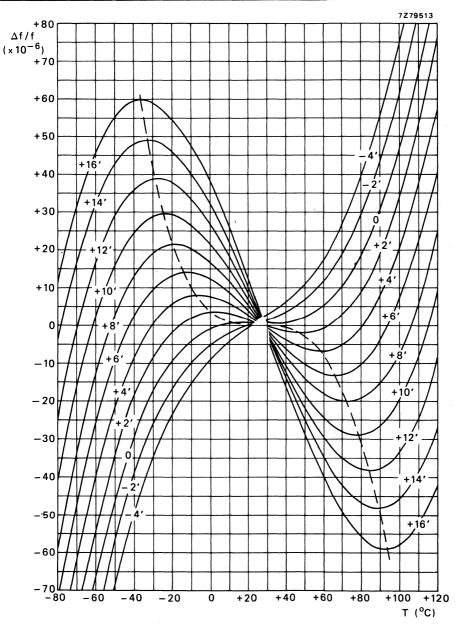


Fig. 5 Frequency/temperature characteristics of a special crystal design.

QUARTZ CRYSTAL UNITS

LEVEL OF DRIVE

The power dissipated in a crystal unit is termed "level of drive" and is usually expressed in mW. In the level of drive range 10⁻¹² to 10⁻³ W the drive level dependency of the crystal unit characteristics is almost negligible. For drive levels greater than approximately 1 mW, the crystal unit characteristics tend to change. For this reason the crystal unit characteristics are specified at a level of drive of 0,5 mW.

Low drive levels

If a crystal unit in an oscillator starts to build up electrical power, low drive levels < 10⁻¹² W may occur depending on the circuit applied. The load resonance resistance R_L and resonance resistance R may increase slightly at these low levels.

High drive levels

For high stable applications drive levels greater than 0,5 mW should be avoided. Excessively high drive levels (> 10 mW) may lead to serious deviations.

FREQUENCY/TEMPERATURE CHARACTERISTICS

The frequency drift as a function of temperature can be represented by a graph, the T.C. curve or drift characteristic. In the case of AT cuts, the relation of drift and temperature is approximated by a cubic curve; the drift characteristic of the other cuts is parabolic in shape.

Figure 5 shows a number of frequency-temperature curves obtained from AT-cut crystals with various angles of cut α (from -4' to + 16' increasing angle of cut). The curves are symmetrical with respect to 27 °C, and it is not possible to shift this point. A temperature range which is fairly symmetrical with respect to 27 °C (e.g. 0 - 60 °C) will, therefore, result in the smallest frequency drift in that range. A small frequency drift over a wide temperature range, e.g. -40 to + 80 °C, will result in a quite steep temperature coefficient at room temperature.

It will be evident that, for AT-cut crystals, the angle of cut and its accuracy are decisive for the frequency drift over a given temperature range.

ADVANTAGES OF ALL-GLASS HOLDERS

Crystal units with all-glass holders show the following advantages over those with metal holders:

- (a) a lower series resistance, which also means a higher Q-factor, thanks to the fact that glass holders are evacuated giving less mechanical damping;
- (b) better performance under adverse climatic conditions;
- (c) a higher frequency stability.

AGEING

A non-reversible, mostly gradual change with time in resonance frequency is called (an effect of) ageing. Only where a very good long-term stability is required should ageing be of consequence. It should be borne in mind that (with a view to ageing only):

- (a) crystal units having an all-glass holder are favourable compared with those having a metal holder;
- (b) low frequency crystals are favourable compared with high frequency crystals having the same crystal cut;
- (c) overtone crystals are favourable compared with fundamental crystals for the same frequency (or fifth overtone compared with third overtone crystals).

CRYSTAL BEHAVIOUR IN AN OSCILLATOR

In the vicinity of resonance the impedance of a quartz crystal unit can be represented by a circle (see Fig. 6). The circle is shifted downwards with respect to the resistance axis over

$$X_0 = \frac{1}{2\pi f_r C_0}.$$

When a load capacitance is connected in series with the unit the shift is $X_0 + X_L$, where

$$X_{L} = \frac{1}{2\pi f_{1} C_{1}}.$$

The frequency difference between anti-resonance frequency and resonance frequency

$$\mathsf{f}_a - \mathsf{f}_r \approx \frac{\mathsf{C}_1}{2\mathsf{C}_0} \cdot \mathsf{f}_r \cdot \frac{\mathsf{C}_L}{\mathsf{C}_0 + \mathsf{C}_L}$$

is assumed to be 100%.

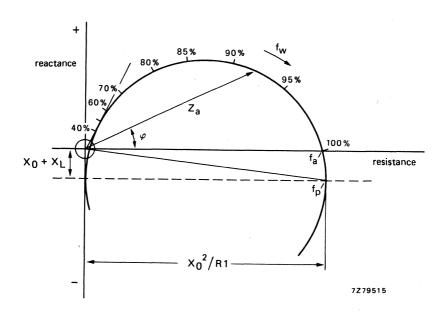
It can be seen that the frequency difference between the two frequencies, determined by the phase angle φ , disappears at $f_W = 50\%$. The phase angle in the oscillator should be kept sufficiently small to avoid crystal unit operation in the uncertain 50% area (frequency switching).

Quartz crystal units for frequencies higher than 100 to 125 MHz (depending on type) have an impedance circle with a greater downwards shift, even to below the real axis. When the figure of merit given by

$$M = \frac{X_0}{R_1} = \frac{1}{(2\pi f_r) R_1 C_0}$$

is less than approximately 5, the resonance frequency fr is arbitrary.





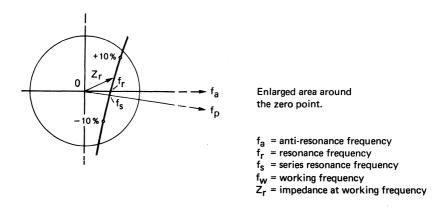


Fig. 6 Working frequency and impedance of a quartz crystal unit in the impedance diagram.

Indications for use

Keep phase deviations in the circuit sufficiently low to avoid crystal unit operation in the 50% working frequency area, in particular when phase variation is used for frequency pulling (P.L.L. system).

Ensure that amplification is sufficiently high, in particular when applying phase variation.

Keep crystal unit drive level low (generally ≤ 0,5 mW), see Fig. 7.

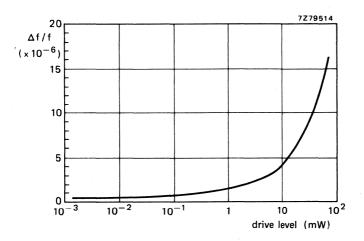


Fig. 7.

MEASURING PROCEDURES

Several methods of measuring quartz crystal units are in use.* Because different methods may give different results, our measuring procedure is given below. This is the passive method with π -network according to IEC publication 444. Further, the method is mentioned with crystal test oscillator type 150A, make Saunders, which is recommended if a frequency correlation of 2 to 5 ppm is tolerable. The accuracy of reproduction of the π -network method ranges between 10-6 and 10-8 depending on the type of crystal unit to be measured. The π -network method can be extended for measuring crystal unit parameters very accurately. This is achieved by a slight modification of the π -network, the use of precision reference resistors and two precision high-frequency load capacitors.

PASSIVE METHOD WITH π -NETWORK (IEC)

The principle of this method is very simple. With the equipment shown in the block diagram of Fig. 1, a stable signal source (frequency synthesizer) is adjusted to the frequency at which the signal has zero phase change when passing through the crystal as measured by the phase meter; this frequency (measured with the frequency counter) is then the resonance frequency of the crystal.

For ease of operation, it is possible to phase-lock the system by feeding back the analogue output of the phase error (from zero) to control the precise frequency of the signal source (A.F.C. loop shown by dashed line).

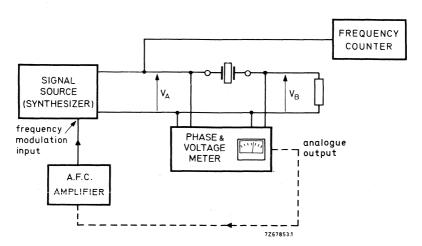


Fig. 1.

* The following measuring methods can be applied on request for the time the obsolete equipment is available:

Method using Crystal Test Set, type TS193A (British Military Standard).

Method using Crystal Impedance Meter T\$330/TSM (U.S. Army Standard).

Method using Crystal Impedance Meter TS683/TSM (U.S. Army Standard).

π-network

The first departure which must be made from the simple system of Fig. 1 is the test jig for holding the crystal. The test jig consists of two π -connected resistive pads, carefully manufactured to represent a pure, constant resistance, which is frequency insensitive at the terminals of the quartz crystal (see Fig. 2).

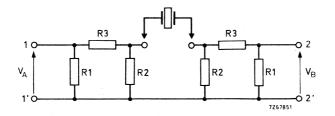


Fig. 2.

The function of the input and output'pads' is twofold:

- (a) to match the crystal impedance to the associated equipment,
- (b) to attenuate reflections from the associated equipment.

For further particulars consult IEC recommendations, Publication 444.

Quartz crystal parameter measurements

A 5 pF trimming capacitor should be connected in parallel with each of the resistors R2 for accurate compensation of the transmission circuit. A shield is mounted between the contacting plates to reduce the capacitance between them. Two measuring procedures for crystal parameter measurement with the modified π -network are in use:

The C_L method

In general, this method is used for fundamental mode crystal units with frequencies up to 25 MHz.

Precision load capacitors are inserted in the π -network. Load resonance frequency and load resonance resistance can then be measured directly. C1 can be calculated.

The impedance method

Generally this method is used for higher frequencies up to approximately 125 MHz.

Phase and impedance are measured, all other parameters can be calculated by means of a computer.

Crystal shielding

Depending on the application, crystal shielding may give rise to frequency deviations, in particular for fundamental mode crystal units with a considerable pulling sensitivity.

In our procedure the metal enclosure of the crystal unit normally is not earthed. If, in special cases, earthing is required this should be mentioned in the specification for ordering.

METHOD WITH CRYSTAL TEST OSCILLATOR 150A AND PRINTER PROCESSOR 2000A Initial calibration

The accuracy of the crystal test oscillator is for a considerable part determined by the alignment of the capacitance meter. Alignment and check of the capacitance meter by means of a stable precision 75 pF capacitor is recommended. For further particulars see 150 A manual.

HOLDERS

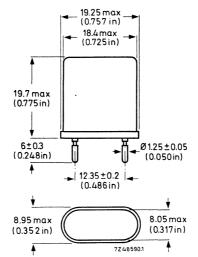
The following holders state the nominal frequency by means of 7 (or 8) figures, in kHz in the case of fundamental crystals and in MHz in the case of overtone crystals. Other figures on the faces constitute registration numbers that relate to the date and series of manufacture.

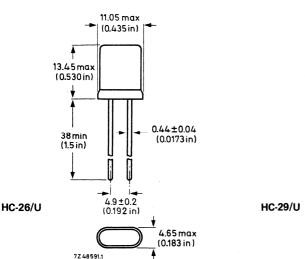
ALL-GLASS HOLDERS

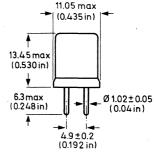
Dimensions in mm (in inches between brackets)

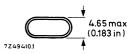
HC-27/U

(IEC type DB is identical except for the height which is 26 mm max. instead of 19.7 max.).





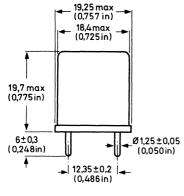


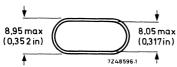




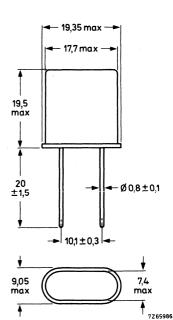
METAL HOLDERS

Dimensions in mm (in inches between brackets)



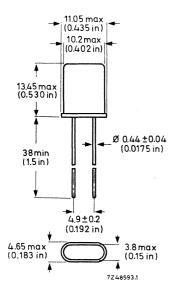


HC-6/U, solder sealed RW-36, resistance welded

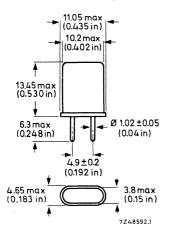


RW-10 resistance welded

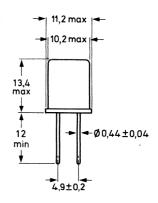


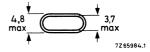


HC-18/U solder sealed

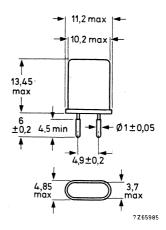


HC-25/U solder sealed





RW-43 resistance welded



RW-42 resistance welded

QUARTZ CRYSTAL UNITS

CORRESPONDING IEC AND DIN TYPE NUMBERS

	IEC 122-3	DIN 45110
HC-6/U	AA	K1A
HC-18/U	BC	M2A
HC-25/U	CX	M1A
HC-26/U	CY	R2A
HC-27/U	DA	Q1A
HC-29/U	CZ	R1A
(height 26 mm max.)	DB	Q1B
RW-10	DS	K4A
RW-36	_	K3A
RW-42	DQ	МЗА
RW-43	DP	M4A

HOW TO SPECIFY A QUARTZ CRYSTAL UNIT

For quotation or ordering a quartz crystal unit which still has no complete catalogue number (12 digits), the supplier needs to know certain basic information. Please use the following check list.

Type of crystal unit

Type of holder

Nominal frequency

kHz

Mode of vibration

fundamental or $\frac{\text{third}}{\text{fifth}}$ overtone

to

Allowable deviation from nominal frequency (adjustment tolerance) at + 25 °C

x 10⁻⁶

-

oc

Temperature range from Frequency drift over specified temperature range $\times 10^{-6}$

Circuit conditions:

resonance frequency f_r or load resonance frequency f_L and load capacitance C_L maximum resonance resistance R or maximum load resonance resistance R_L

kHz pF Ω

kHz

Ω

Crystal unit equivalent parameters

Mechanical requirements/tests

C1
C0
R1
L1
Level of drive
Ageing $\Delta f/f$ per month or year

fF pF

Ω mH

mW

x 10⁻⁶





QUARTZ CRYSTAL UNITS FOR SPECIAL APPLICATIONS

R

TESTS AND REQUIREMENTS

Applicable to all units in RW-43 holder, with catalogue number 4322 143 0 \ldots

IEC 122	IEC 68-2	test	procedures	requirements
2.5.17	Ва	aging	1000 h +100 °C	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.
2.5.12 2.5.13 2.5.14	Db	accelerated damp heat	+ 25 to + 55 °C, 6 cycles 95 to 100% R.H.	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.
-	Na	temperature cycling test	-40/+ 125 °C, 10 cycles, 1 h/cycle.	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.
2.5.2	Ea	shock	100g sawtooth 6 shocks, 3 directions	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.
2.5.3	Fc	vibration	10-500-10 Hz, 10g, 3 h, 3 directions.	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.
	Tb	resistance to soldering heat	3 s, 350 °C.	≤ 5 x 10 ⁻⁶ . ≤ 20%.
2.5.6	Ub	bending of terminations	1 x 90°, 5 N.	no visible damage.
	Eb	bump	3000 bumps, 30g	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.
	Ed	free fall	3 x 0,75 m on steel	$\Delta f_r \le 5 \times 10^{-6}$. $\Delta R \le 20\%$.



QUICK REFERENCE DATA

Nominal frequency	8 867,238 kHz
Mode of vibration	fundamental
Type of holder	RW-10

APPLICATION

Intended to be used in the sub-carrier oscillator of colour television sets according to the PAL system.

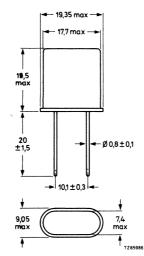
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass



The frequency in kHz, the last 5 digits of the catalogue number and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly into a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f_L, load capacitance 20 pF

Adjustment tolerance

Tolerance over the temperature range of + 10 to + 60 °C, with respect to + 25 °C

Trimability at a load cap. of 20 pF with a load cap. variation of 10 pF

Motional capacitance (C₁)
Parallel capacitance (C₀)

- araner capacitance (of

Resonance resistance in temperature range of + 10 to + 60 °C

Maximum permissible d.c. voltage between terminations

Operating temperature range

8 867, 238 kHz ± max. 40 x 10⁻⁶

± max. 30 x 10⁻⁶

min. 950 Hz

typ. 21 fF

max. 6 pF, typ. 5 pF

typ. 15 Ω max. 60 Ω

100 V

+ 10 to + 60 °C



TESTS AND REQUIREMENTS

Essentially the following tests mentioned in the schedule of IEC publication 122 are carried out along the lines of IEC publication 68.

IEC 122 clause	IEC 68-2 test method	test	procedure	requirements
2.5.17	· _	aging	30 days, + 85 °C	$\Delta f/f \pm \text{max. } 15 \times 10^{-6}$
2.5.12	Db	damp heat accelerated	1 day, + 55 °C 100% R.H.	$\Delta f/f \pm max. 10 \times 10^{-6}$ R _{ins} at 50 V d.c. min. 20 M Ω
	Na	rapid change of temperature	-20/+ 50 °C 15 cycles 1 h per cycle	$\Delta f/f \pm \text{max. } 5 \times 10^{-6}$
2.5.2	Ea	shock	40g, sawtooth 6 directions, 1 blow per direction	$\Delta f/f \pm max. 5 \times 10^{-6}$ $\Delta R/R \pm max. 15\%$
2.5.3	Fc	vibration	10-55-10 Hz, 0,75 mm displacement 2 h, 3 directions*	$\Delta f/f \pm max. 5 \times 10^{-6}$ $\Delta R/R \pm max. 15\%$
2.5.6	Ub	flexibility of terminations	1 x 90°, 5 N	no visible damage
2.5.10	Т	soldering	300 °C, 2 s	Δf/f ± max. 2 x 10 ⁻⁶ good tinning no visible damage

^{*} The batch is divided into three equal parts, each part is tested in one of the three perpendicular directions.





QUICK REFERENCE DATA

Nominal frequency	4 782,720 kHz
Mode of vibration	fundamental
Type of holder	RW-43

APPLICATION

Two-tone telephone dialling system.

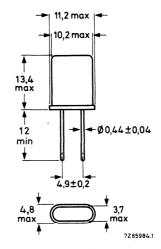
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass 1 g approximately

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 o C and a level of drive of 0,5 mW related to 25 Ω .

Resonance frequency fL

Adjustment tolerance

Tolerance over the temperature range of -20 to + 70 °C, with

respect to + 25 °C

Motional capacitance (C₁)

Parallel capacitance (C₀)

Resonance resistance

Maximum permissible d.c. voltage between terminations

between terminations

Operating temperature range

4 782,720 kHz

± max. 50 x 10⁻⁶

± max. 50 x 10⁻⁶

typ. 21,4 fF typ. 5,8 pF

max. 60 Ω

100 V

 $-20 \text{ to} + 70 ^{\circ}\text{C}$



See page B2.



QUICK REFERENCE DATA

Nominal frequency	4 433,619 kHz
Mode of vibration	fundamental
Type of holder	RW-43

APPLICATION

Intended to be used in the sub-carrier oscillator of colour television sets according to the PAL system.

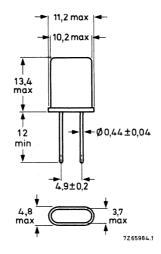
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass



The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega_{\rm c}$

Load resonance frequency fL,

load capacitance 20 pF Adjustment tolerance

Tolerance over the temperature range of -10 to +60 °C, with

respect to + 25 °C

Motional capacitance (C₁)

Parallel capacitance (C₀)

Resonance resistance

Pullability $\left(-\frac{df}{dC}\right)$ at f_L

with load capacitance variation

Maximum permissible d.c. voltage

between terminations

Operating temperature range

4 433,619 kHz

± max. 40 x 10⁻⁶

± max. 30 x 10⁻⁶

typ. 20,4 fF

typ. 5,4 pF

max. $60~\Omega$

min. + $12 \times 10^{-6} \times f_L/pF$

100 V

-10 to +60 °C

TESTS AND REQUIREMENTS

See page B2.



QUICK REFERENCE DATA

Nominal frequency	8 867,238 kHz
Mode of vibration	fundamental
Type of holder	RW-43

APPLICATION

Intended to be used in the sub-carrier oscillator of colour television sets according to the PAL system.

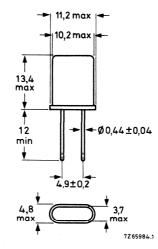
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass 1 g approximately

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f_L, load capacitance 20 pF

Adjustment tolerance

Tolerance over the temperature range of -10 to +60 °C, with respect to +25 °C

Motional capacitance (C₁)

Parallel capacitance (C₀) Resonance resistance

Pullability $\left(-\frac{df}{dC}\right)$ at f_L

with load capacitance variation

Maximum permissible d.c. voltage

between terminations

Operating temperature range

8 867,238 kHz

 \pm max. 40 x 10⁻⁶

± max. 25 x 10⁻⁶

typ. 24 fF

typ. 5,5 pF max. 60 Ω

min. + $16 \times 10^{-6} \times f_L/pF$

100 V

-10 to +60 °C

TESTS AND REQUIREMENTS

See page B2.

DEVELOPMENT SAMPLE DATA

This information is derived from development samples made available for evaluation. It does not form part of our data handbook system and does not necessarily imply that the device will go into production

4322 143 04060

QUARTZ CRYSTAL UNIT

QUICK REFERENCE DATA

Nominal frequency Mode of vibration

fundamental RW-43

4 194,812 kHz

Type of holder

APPLICATION

Quartz clocks, dividing ratio 222: 1 + offset.

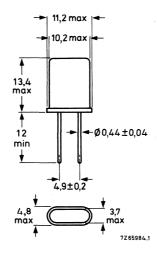
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass



The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 °C and a level of drive of 1 mW related to 25 Ω .

Load resonance frequency f_L,

load capacitance 17 pF

Adjustment tolerance

Tolerance over the temperature range of -40 to +80 °C, with

respect to + 25 °C

Motional capacitance (C_1) Parallel capacitance (C_0)

Resonance resistance

Pullability ($-\frac{df}{dC}$) at f_L

with load capacitance variation

Maximum permissible d.c. voltage between terminations

Operating temperature range

4 194,812 kHz

 \pm max. 40 x 10⁻⁶

± max. 50 x 10⁻⁶

typ. 13 fF

typ. 3,3 pF max. 100 Ω

min. + 11 x 10⁻⁶ x f_L/pF

100 V

-40 to +80 °C

QUICK REFERENCE DATA

Nominal frequency	4 194,304 kHz
Mode of vibration	fundamental
Type of holder	RW-43

APPLICATION

Quartz clocks, dividing ratio 222:1.

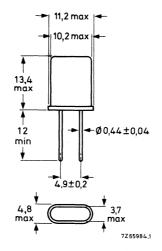
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass 1 g approximately

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{O}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f_L, load capacitance 12 pF

Adjustment tolerance

Tolerance over the temperature range of -10 to +60 °C, with respect to +25 °C

Motional capacitance (C₁)

Parallel capacitance (C₀) Resonance resistance

Pullability $\left(-\frac{df}{dC}\right)$ at f_L

with load capacitance variation

Maximum permissible d.c. voltage between terminations

Operating temperature range

4 194,304 kHz

± max. 40 x 10⁻⁶

± max. 25 x 10⁻⁶

typ. 11,6 fF typ. 2,9 pF

max. 35 Ω , typ. 20 Ω

min. + 22 x 10^{-6} x f_L/pF

100 V

-10 to +60 °C

TESTS AND REQUIREMENTS

See page B2

QUICK REFERENCE DATA

Nominal frequency		9 - 1 • 1 - 1 - 1 - 1 - 1	4 000,000 kHz
Mode of vibration			fundamental
Type of holder			RW-43

APPLICATION

General purpose, e.g. digital tuning.

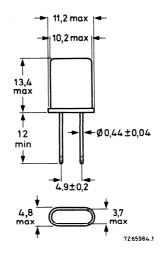
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass 1 g approximately

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega_{\rm c}$

Load resonance frequency fL,

load capacitance 30 pF

Adjustment tolerance

Tolerance over the temperature range of -10 to +60 °C, with respect to +25 °C

Motional capacitance (C₁)

Parallel capacitance (C_O)

Resonance resistance

Pullability $\left(-\frac{df}{dC}\right)$ at f_L

with load capacitance variation

Maximum permissible d.c. voltage between terminations

Operating temperature range

4 000,000 kHz ± max. 40 x 10⁻⁶

± max. 25 x 10⁻⁶

typ. 11 fF

typ. 2,8 pF

max. 60 Ω

min. $+ 5 \times 10^{-6} \times f_1 / pF$

100 V

-10 to +60 °C

TESTS AND REQUIREMENTS

See page B2.



DEVELOPMENT SAMPLE DATA

This information is derived from development samples made available revaluation. It does not form part of our data handbook system and does not necessarily imply that the device will go into production

QUARTZ CRYSTAL UNIT

QUICK REFERENCE DATA

Nominal frequency	6 000,000 kHz
Mode of vibration	fundamental
Type of holder	RW-43

APPLICATION

Teletext and Viewdata.

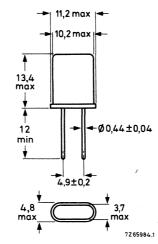
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 ± 2 °C and a level of drive of 0,5 mW related to 25 Ω .

Load resonance frequency fi, load capacitance 20 pF

Adjustment tolerance

Tolerance over the temperature range of -20 to +70 °C, with

respect to + 25 °C

Motional capacitance (C₁)

Parallel capacitance (Co) Resonance resistance

Pullability $\left(-\frac{df}{dC}\right)$ at f_L

with load capacitance variation

Maximum permissible d.c. voltage between terminations

Operating temperature range

TESTS AND REQUIREMENTS

See page B2.

6 000,000 kHz

± max, 40 x 10-6

± max. 30 x 10⁻⁶

typ. 28 fF typ. 7,1 pF

max. $60~\Omega$

min. + $16 \times 10^{-6} \times f_L/pF$

100 V

-20 to +70 °C

QUICK REFERENCE DATA

Nominal frequency	4 433,619 kHz
Mode of vibration	fundamental
Type of holder	RW-10

APPLICATION

Intended to be used in the sub-carrier oscillator of colour television sets according to the PAL system.

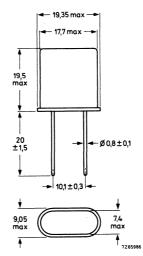
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass

The frequency in kHz, the last 5 digits of the catalogue number and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly into a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f _L ,	
load capacitance 20 pF	4 433,619 kHz
Adjustment tolerance	± max. 40 x 10 ⁻⁶
Tolerance over the temperature range of + 10 to + 60 °C, with respect to + 25 °C	± max. 30 x 10 ⁻⁶
Trimability at a load cap. of 20 pF with a load cap. variation of 10 pF	min. 600 Hz
Motional capacitance (C ₁)	typ. 29 fF
Parallel capacitance (C ₀)	max. 7 pF, typ. 6,5 pF
Resonance resistance in temperature range of + 10 to + 60 °C	typ. 15 Ω max. 50 Ω
Maximum permissible d.c. voltage between terminations	100 V
Operating temperature range	+ 10 to + 60 °C

TESTS AND REQUIREMENTS

Essentially the following tests mentioned in the schedule of IEC publication 122 are carried out along the lines of IEC publication 68.

IEC 122 clause	IEC 68-2 test method	test	procedure	requirements
2.5.17	· _	aging	30 days, + 85 °C	$\Delta f/f \text{ max. } 15 \times 10^{-6}$
2.5.12	Db	damp heat accelerated	1 day, + 55 °C 100% R.H.	$\Delta f/f$ max. 10 x 10 ⁻⁶ R _{ins} at 50 V d.c. min. 20 M Ω
	Na	rapid change of temperature	-20/+ 50 °C 15 cycles 1 h per cycle	$\Delta f/f \pm max. 5 \times 10^{-6}$
2.5.2	Ea	shock	40g, sawtooth 6 directions, 1 blow per direction	$\Delta f/f \pm max. 5 \times 10^{-6}$ $\Delta R/R \pm max. 15\%$
2.5.3	Fc	vibration	10-55-10 Hz, 0,75 mm displacement 2 h, 3 directions*	$\Delta f/f \pm max. 5 \times 10^{-6}$ $\Delta R/R \pm max. 15\%$
2.5.6	Ub	flexibility of terminations	1 x 90°, 5 N	no visible damage
2.5.10	Т	soldering	300 °C, 2 s	$\Delta f/f \pm max. 2 \times 10^{-6}$ good tinning no visible damage

^{*} The batch is divided into three equal parts, each part is tested in one of the three perpendicular directions.



QUICK REFERENCE DATA

Nominal frequency	10 MHz
Mode of vibration	third overtone
Type of holder	all-glass, HC-27/U

APPLICATION

For frequency stabilization in circuits in which a high stability and a low series resistance are required.

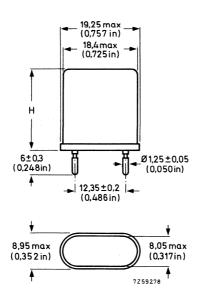
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed, evacuated glass holder, provided with two connecting pins.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit is provided with pins for socket mounting.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of +25 ± 2 °C and a level of drive of 1 mA.*

Load resonance frequency fL,

load capacitance 75 pF**

10 000 kHz

Adjustment tolerance

± max. 5 x 10⁻⁶

Tolerance over the temperature range of +69 to +71 °C,

with respect to +25 °C

 \pm max. 3 x 10^{-7} typ. 2,1 fF

Motional capacitance (C₁)

-,,,,,,,

Parallel capacitance (C₀)
Motional inductance (L₁)

typ. 5 pF typ. 120 mH

Resonance resistance over the temperature range of

-40 to +75 °C

max, 40 Ω

Maximum permissible d.c. voltage between terminations

100 V

Aging
Operating temperature range

 $\pm 5 \times 10^{-8}$ /month -40 to +75 °C

Stability of oscillator frequency. This depends on the crystal oven used. Stability figures of 1 \times 10⁻⁶ to 1 \times 10⁻⁷ can be achieved.

TESTS AND REQUIREMENTS

According to MIL-C-3098C.

 $\Delta f/f$

± max. 3 x 10⁻⁶

 $\Delta R/R$

± max. 15%

^{*} Influence of drive level on frequency is max. 2 x 10⁻⁸/dB.

^{**} Data at other C₁ and for series resonance available on request.

DEVELOPMENT SAMPLE DATA

This information is derived from development samples made available for evaluation. It does not form part of our data handbook system and does not necessarily imply that the device will go into production

QUARTZ CRYSTAL UNIT

QUICK REFERENCE DATA

Nominal frequency 5000 kHz
Mode of vibration fundamental
Type of holder RW-43

APPLICATION

Television cameras.

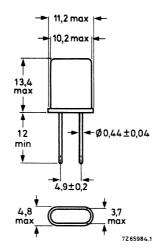
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in a hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass

The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 °C and a level of drive of 0,5 mW related to 25 $\Omega.$

Load resonance frequency f_L,

load capacitance 20 pF

Adjustment tolerance

Tolerance over the temperature range of -20 to + 70 °C, with

respect to + 25 °C

Motional capacitance (C₁)

Parallel capacitance (Cn)

Resonance resistance

Pullability $\left(-\frac{df}{dC}\right)$ at f_L

with load capacitance variation

Maximum permissible d.c. voltage

between terminations

Operating temperature range

5000 kHz

 \pm max. 40 x 10⁻⁶

 \pm max. 30 x 10⁻⁶ typ. 14,4 fF

typ. 3,3 pF

max. 60Ω

min. + 12 x 10⁻⁶ x f₁ /pF

100 V

-20 to + 70 °C

DEVELOPMENT SAMPLE DATA

This information is derived from development samples made available for evaluation. It does not form part of our data handbook system and does not necessarily imply that the device will go into production

QUARTZ CRYSTAL UNIT

QUICK REFERENCE DATA

Nominal frequency 5120 kHz

Mode of vibration fundamental

Type of holder RW-43

APPLICATION

Car radios.

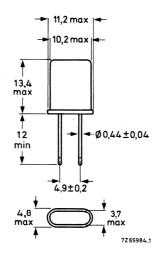
DESCRIPTION

The unit consists of a metal-plated AT-cut quartz plate, mounted in hermetically sealed resistance welded metal holder, provided with two connecting leads.

MECHANICAL DATA

Outlines

Dimensions in mm



Mass



The frequency in kHz, the last 5 digits of the catalogue number, and a code for the date of manufacture are stamped on the holder.

Mounting

The unit can be soldered directly onto a printed-wiring board.

ELECTRICAL DATA

Unless otherwise specified the values apply at a temperature of 25 \pm 2 ^{o}C and a level of drive of 0,5 mW related to 25 $\Omega_{\rm c}$

Load resonance frequency f_L, load capacitance 20 pF

load capacitance 20 p

Adjustment tolerance

Tolerance over the temperature

range of -20 to +70 °C, with respect to +25 °C

Motional capacitance (C₁)

Parallal canonitanae (Ca)

Parallel capacitance (C₀)

Resonance resistance

Pullability ($-\frac{df}{dC}$) at f_L

with load capacitance variation

Maximum permissible d.c. voltage

between terminations

Operating temperature range

5120 kHz

 \pm max. 40 x 10⁻⁶

± max. 30 x 10⁻⁶

typ. 14,6 fF

typ. 3,2 pF

max. 60 Ω

min. + 15 x 10⁻⁶ x f_L/pF

100 V

-20 to + 70 °C



QUARTZ CRYSTAL UNITS FOR GENERAL FREQUENCY STABILIZATION

C



QUICK REFERENCE DATA

Frequency range 4 to 10 MHz
Mode of vibration fundamental
Type of holder RW-10 or RW-36

MECHANICAL DATA

Outlines

See general section (A) "Holders".

Mass

4 g

ELECTRICAL DATA

Frequency tolerance with respect to + 25 °C in temperature range:

 $\begin{array}{lll} 0 \text{ to} + 60 \text{ }^{\circ}\text{C} & \pm \text{ max. } 30 \times 10^{-6} \\ -30 \text{ to} + 80 \text{ }^{\circ}\text{C} & \pm \text{ max. } 35 \times 10^{-6} \\ + 15 \text{ to} + 45 \text{ }^{\circ}\text{C} & \pm \text{ max. } 10 \times 10^{-6} \end{array}$

Maximum permissible d.c. voltage

between terminations 100 V

Aging within adjustment tolerance

^{*} Data at other C_L values and for series resonance available on request.

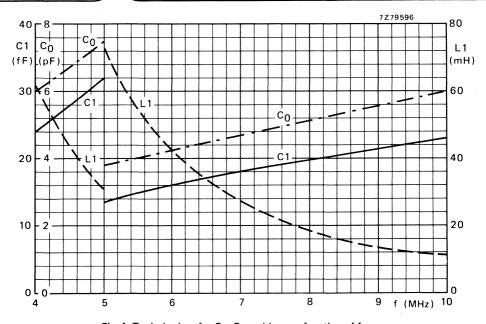


Fig. 1 Typical values for C_0 , C_1 and L_1 as a function of frequency.

TESTS AND REQUIREMENTS

test	IEC-122 clause	IEC-68-2 test method	procedure	requirements
aging	2.5.17	_	30 days + 85 °C	$\Delta f/f \leq 10 \times 10^{-6}$
acceleration	2.5.12 2.5.13 2.5.14	Db		$\Delta f/f \le 10 \times 10^{-6}$ R _{ins} > 20 M Ω at 50 V (d.c.)
temperature cycling	_	Na	-20/+ 50 °C, 15 cycles, 1 h/cycle	$\Delta f/f \leqslant 5 \times 10^{-6}$
shock	2.5.2	Ea	100g sawtooth 6 directions, 1 blow/direction	$\Delta f/f \le 5 \times 10^{-6}$ $\Delta R/R < 15\%$
vibration	2.5.3	Fc	10-55-10 Hz 2 hours*	$\Delta f/f \le 5 \times 10^{-6}$ $\Delta R/R < 15\%$
soldering**	2.5.10	T		no visible damage, terminals well-tinned $\Delta f/f \leqslant 2 \times 10^{-6}$
bending of terminations**	2.5.6	Ub	1 x 90°, 5 N	no visible damage

^{*} The batch is divided into 3 equal parts, each part is tested in 1 of the 3 perpendicular directions.

^{**} Holder RW-10 only.

QUICK REFERENCE DATA

Frequency range 1.6 to 25 MHz Mode of vibration fundamental Type of holder RW-36

MECHANICAL DATA

Outlines

See general section (A) "Holders".

Mass

4 g

ELECTRICAL DATA

 $\pm 20 \times 10^{-6}$ Adjustment tolerance at + 25 °C Load capacitance C₁ * 30 pF Level of drive 0,5 mW Motional capacitance C₁ 5 to 30 fF max, 7 pF Parallel capacitance Co. Resonance resistance R₁ see Table 1

Frequency tolerance in different

temp. ranges with respect to + 25 °C

Maximum permissible d.c. voltage

between terminations

Aging

TESTS

Mechanical and climatic tests

within adjustment tolerance

according to MIL and IEC procedures

see Table 2

100 V

^{*} Data at other C_L values and for series resonance available on request.

Table 1 Resonance resistance R₁

frequency MHz	max. R_1
1,600000 — 1,999999	300
2,000000 - 2,249999	250
2,250000 - 3,749999	150
3,750000 - 4,999999	100
5,000000 - 6,999999	50
7,000000 - 9,999999	30
10,000000 — 25,000000	25

Table 2 Frequency tolerance in different temperature ranges with respect to + 25 °C

frequency range MHz	temperature	frequency tolerance			
	oC range	class 0	class I	class II	
1,6 - 25	-5/+ 45 -10/+ 50 -15/+ 70	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶	
1,6 - 2,3 2,3 - 4 4 - 25	-55/+ 105 -55/+ 105 -55/+ 105	± 30 × 10 ⁻⁶ ± 32,5 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 35 × 10 ⁻⁶ ± 35 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶	
1,6 - 25	T _{nom} ± 5		± 5 x 10 ⁻⁶		

QUICK REFERENCE DATA

Frequency range 1,6 to 25 MHz
Mode of vibration fundamental
Type of holder HC-6/U

MECHANICAL DATA

Outlines

See general section (A) "Holders".

Mass

4 g

ELECTRICAL DATA

Frequency tolerance in different

temp. ranges with respect to + 25 °C

Maximum permissible d.c. voltage

between terminations

Aging

100 V

see Table 2

within adjustment tolerance

TESTS

Mechanical and climatic tests

according to MIL and IEC procedures

^{*} Data at other C_L values and for series resonance available on request.

frequency MHz	max. R_1
1,600000 — 1,999999	300
2,000000 - 2,249999	250
2,250000 - 3,749999	150
3,750000 - 4,999999	100
5,000000 - 6,999999	50
7,000000 - 9,999999	30
10,000000 — 25,000000	25

Table 2 Frequency tolerance in different temperature ranges with respect to + 25 °C

frequency	temperature	frequency tolerance		
range MHz	oC range	class 0	class I	class 11
1,6 - 25	-5/+ 45 -10/+ 50 -15/+ 70	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶
1,6 - 2,3 2,3 - 4 4 - 25	-55/+ 105 -55/+ 105 -55/+ 105	± 30 × 10 ⁻⁶ ± 32,5 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 35 × 10 ⁻⁶ ± 35 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
1,6 - 25	T _{nom} ±5		± 5 x 10 ⁻⁶	



=

QUARTZ CRYSTAL UNIT

QUICK REFERENCE DATA

Frequency range 1,6 to 25 MHz
Mode of vibration fundamental

Type of holder
1,6 to 2,3 MHz
2,4 to 25 MHz
DB (26 mm)
HC-27/U

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 2,5 g

ELECTRICAL DATA

Adjustment tolerance at + 25 $^{\circ}$ C \pm 10 x 10⁻⁶

Load capacitance C_L^* 30 pF Level of drive 0,5 mW

Motional capacitance C₁ see Figs 1 to 4

Parallel capacitance Co max. 7 pF, see also Fig. 1

Motional inductance L₁ see Figs 1 to 4

Resonance resistance R₁ see Table 1

Frequency tolerance in different temperature

ranges with respect to + 25 °C see Table 2

Maximum permissible d.c. voltage

between terminations 100 V

Aging after 90 days non-operative at $+ 85 \pm 2$ °C (-0.5 to + 1) x 10^{-6}

TESTS

^{*} Data at other C_L values and for series resonance available on request.

Table 1 Resonance resistance R₁

max. R $_1$
220
185
165
150
125
90
70
52
45
37
25
20
18
15

Table 2, Frequency tolerance in different temperature ranges with respect to + 25 °C

frequency	temperature		frequency tolerance	
range MHz	oC range	class 0	class I	class II
1,6 - 25	-5/+ 45 -10/+ 50 -15/+ 70	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶
1,6 - 2,3 2,3 - 7 7 - 25	-55/+ 105 -55/+ 105 -55/+ 105	± 30 × 10 ⁻⁶ ± 32,5 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 35 x 10 ⁻⁶ ± 35 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 40 x 10 ⁻⁶ ± 40 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
1,6 - 25	T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 x 10 ⁻⁶



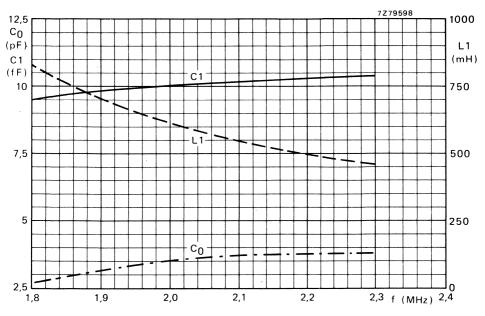


Fig. 1 Typical values for C_0 , C_1 and L_1 for frequencies from 1,8 to 2,3 MHz.

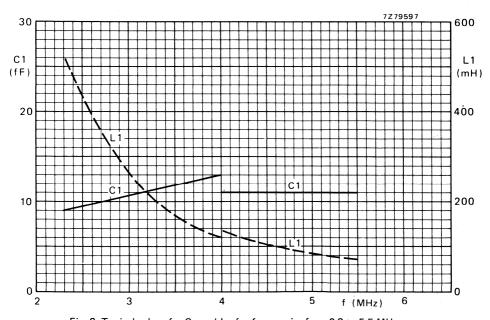


Fig. 2 Typical values for C₁ and L₁ for frequencies from 2,3 to 5,5 MHz.

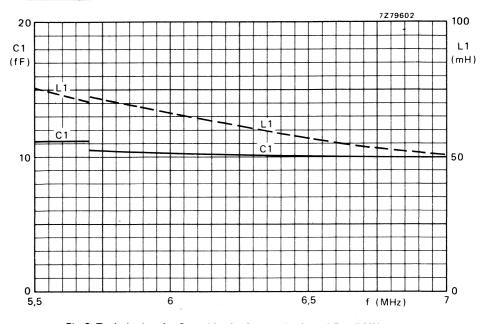


Fig. 3 Typical values for C_1 and L_1 for frequencies from 5,5 to 7 MHz.

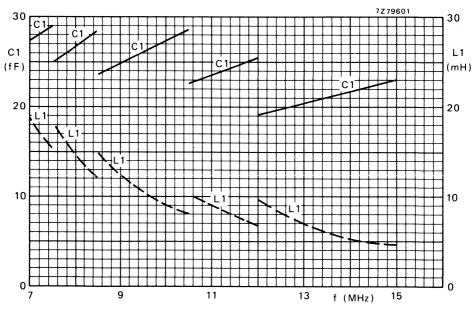


Fig. 4 Typical values for C_1 and L_1 for frequencies from 7 to 15 MHz.



QUICK REFERENCE DATA

Frequency range

4 to 25 MHz

Mode of vibration

fundamental

Type of holder

HC-26/U or HC-29/U

MECHANICAL DATA

Outlines

See general section (A) "Holders".

Mass

0,8 q

ELECTRICAL DATA

Adjustment tolerance at + 25 °C

± 10 x 10-6

Load capacitance C₁ *

30 pF

Level of drive

0,5 mW

Motional capacitance C₁

see Figs 1 and 2

Parallel capacitance Co.

Motional inductance L₁

see Table 1

Resonance resistance R₁

Frequency tolerance in different temperature ranges with respect to + 25 °C

see Table 2

Maximum permissible d.c. voltage

between terminations

100 V

Aging after 90 days non-operative

at + 85 ± 2 °C

 $(-0.5 \text{ to} + 1) \times 10^{-6}$

TESTS



^{*} Data at other C₁ values and for series resonance available on request.

frequency max. R Ω	
4 .	max. R $_1$
4,000000 - 4,749999 110 4,750000 - 5,999999 70 6,000000 - 6,999999 45 7,000000 - 9,999999 30 10,000000 - 14,999999 25	70 45 30 25
15,000000 — 25,000000 20	20

Table 2 Frequency tolerance in different temperature ranges with respect to + 25 °C

frequency	temperature	+	frequency tolerance	
range MHz	oC range	class 0	class I	class II
4 - 25	-5/+ 45 -10/+ 50 -15/+ 70	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶
4 - 6 6 - 12 12 - 25	-55/+ 105 -55/+ 105 -55/+ 105	± 30 × 10 ⁻⁶ ± 32,5 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 40 × 10 ⁻⁶ ± 35 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 50 x 10 ⁻⁶ ± 40 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
4 - 25	T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 × 10 ⁻⁶



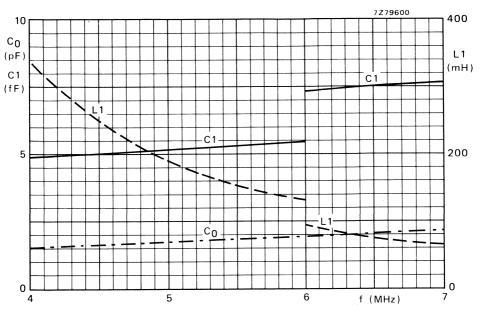


Fig. 1 Typical values of L_1 , C_0 and C_1 for frequencies from 4 to 7 MHz.

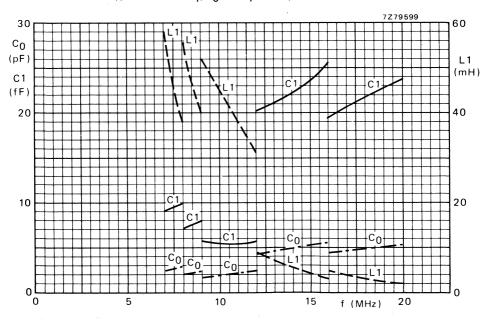


Fig. 2 Typical values of L_1 , C_0 and C_1 for frequencies from 7 to 20 MHz.



QUICK REFERENCE DATA

Frequency range 4 to 25 MHz
Mode of vibration fundamental
Type of holder RW-43 or RW-42

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 1 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C \pm 20 x 10⁻⁶ Load capacitance C_L * 30 pF Level of drive 0,5 mW Motional capacitance C₁ 5 to 30 fF Parallel capacitance C₀ max. 7 pF Resonance resistance R₁ 4 to 7 MHz max. 80 Ω

7 to 25 MHz $$\rm max.~40~\Omega$$ Frequency tolerance in different temperature

ranges with respect to + 25 °C see Table

Maximum permissible d.c. voltage between terminations 100 V

Aging within adjustment tolerance

^{*} Data at other C_L values and for series resonance available on request.

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	fre	equency tolerance	
oC 	class 0	class I	class II
-5/+ 45 -10/+ 50 -15/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
T _{nom.} ± 5	± 5 :	x 10 ⁻⁶	

TESTS AND REQUIREMENTS

test	IEC-122 clause	IEC-68-2 test method	procedure	requirements
aging	2.5.17	_	30 days + 85 °C	$\Delta f/f \pm < 10 \times 10^{-6}$
damp heat, accelerated	2.5.12 2.5.13 2.5.14	D	_	$\Delta f/f \pm < 10 \times 10^{-6}$ R _{ins} > 20 M Ω at 50 V d.c.
temperature cycling	_	Na	-20/+ 50 °C, 15 cycles, 1 h/cycle	$\Delta f/f \pm < 5 \times 10^{-6}$
shock	2.5.2	Ea	100g sawtooth 6 directions, 1 blow/direction	$\Delta f/f \pm < 5 \times 10^{-6}$ $\Delta R \pm < 15\%$
vibration	2.5.3	Fc	10-55-10 Hz 2 h *	$\Delta f/f \pm < 5 \times 10^{-6}$ $\Delta R \pm < 15\%$
soldering**	2.5.10	Т	_	no visible damage, terminals well-tinned $\Delta f/f \pm < 2 \times 10^{-6}$
bending of terminations**	2.5.6	Ub	1 x 90°, 5 N	no visible damage

^{*} The batch is divided into 3 equal parts, each part is tested in 1 of the 3 perpendicular directions.

^{**} Holder RW-43 only.

QUICK REFERENCE DATA

Frequency range	10 to 61 MHz	
Mode of vibration	third overtone	
Type of holder	HC-6/U	

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 4 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	$\pm 20 \times 10^{-6}$
Level of drive	0,5 mW
Motional capacitance C ₁	typ. 1,5 fF
Parallel capacitance C ₀	max. 7 pF
Resonance resistance R ₁	max. 60 Ω
Frequency tolerance in different temperature ranges with respect to + 25 °C	see Table

Maximum permissible d.c. voltage

between terminations

Aging within adjustment tolerance

100 V

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature range	fre	quency tolerance	
oC	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 5 × 10 ⁻⁶	<u></u>

=

QUARTZ CRYSTAL UNIT

QUICK REFERENCE DATA

Frequency range	10 to 61 MHz
Mode of vibration	third overtone
Type of holder	HC-27/U

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 2,5 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	$\pm 10 \times 10^{-6}$
Level of drive	0,5 mW
Motional capacitance C ₁	typ. 1,5 fF
Parallel capacitance C ₀	max. 7 pF
Resonance resistance R ₁	max. 40 Ω
Frequency tolerance in different temperature ranges with respect to + 25 °C	see Table

Maximum permissible d.c. voltage between terminations 100 V

Aging after 90 days non-operative at + 85 \pm 2 $^{\circ}$ C (-0,5 to + 1) \times 10 $^{-6}$

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	fre	quency tolerance	,
oC range	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 x 10 ⁻⁶

QUICK REFERENCE DATA

Frequency range	20 to 61 MHz
Mode of vibration	third overtone
Type of holder	HC-26/U or HC-29/U

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 0,8 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	$\pm 10 \times 10^{-6}$
Level of drive	0,5 mW
Motional capacitance C ₁	typ. 1,5 fF
Parallel capacitance C ₀	max. 7 pF
Resonance resistance R ₁	max. 30 Ω
Frequency tolerance in different temperature ranges with respect to + 25 °C	see Table
Maximum permissible d.c. voltage between terminations	100 V
Aging after 90 days non-operative at $+ 85 \pm 2$ °C	$(-0.5 \text{ to} + 1) \times 10^{-6}$

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance		
oC	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 13 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 x 10 ⁻⁶

QUICK REFERENCE DATA

Frequency range	17 to 61 MHz
Mode of vibration	third overtone
Type of holder	RW-43 or RW-42

MECHANICAL DATA

'Outlines See general section (A) "Holders".

Mass

ELECTRICAL DATA

Adjustment tolerance at + 25 °C	± 20 x 10 ⁻⁶
Level of drive	0,5 mW
Motional capacitance C ₁	typ. 1,5 fF
Parallel capacitance C ₀	max. 7 pF
Resonance resistance R ₁	max. 40 Ω
Frequency tolerance in different temperature ranges with respect to + 25 °C	see Table

Maximum permissible d.c. voltage between terminations

100 V

Aging within adjustment tolerance

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance		
range °C	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶
T _{nom} ± 5		± 5 × 10 ⁻⁶	

QUICK REFERENCE DATA

10 to 61 MHz Frequency range Mode of vibration third overtone RW-36 Type of holder

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass

ELECTRICAL DATA

Adjustment tolerance at + 25 °C ± 20 x 10⁻⁶ 0,5 mW Level of drive typ. 1,5 fF Motional capacitance C₁ Parallel capacitance Co. max. 7 pF max. 60Ω Resonance resistance R₁

Frequency tolerance in different temperature ranges with respect to + 25 °C

Maximum permissible d.c. voltage

between terminations

within adjustment tolerance

see Table

100 V

Aging **TESTS**

Mechanical and climatic tests according to MIL and IEC procedures.

temperature	frequency tolerance		
oC range	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 5 x 10 ⁻⁶	



QUICK REFERENCE DATA

Frequency range 50 to 125 MHz
Mode of vibration fifth overtone
Type of holder HC-6/U

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 4

ELECTRICAL DATA

Adjustment tolerance at + 25 °C \pm 20 x 10⁻⁶ Level of drive 0,5 mW Motional capacitance C₁ typ. 0,5 fF Parallel capacitance C₀ max. 7 pF Resonance resistance R₁ 20 to 100 Ω

Fréquency tolerance in different temperature ranges with respect to + 25 °C

Maximum permissible d.c. voltage

waximum permissible d.c. voltage

between terminations

Aging within adjustment tolerance

see Table

100 V

TESTS

Mechanical and climatic tests according to MIL and IEC procedures.

temperature	frequency tolerance		-
range °C	class 0	ciass i	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	±10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 5 × 10 ⁻⁶	ter en



QUICK REFERENCE DATA

Frequency range	50 to 125 MHz
Mode of vibration	fifth overtone
Type of holder	HC-27/U

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 2.5 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C \pm 10 x 10⁻⁶ Level of drive 0,5 mW Motional capacitance C₁ typ. 0,5 fF Parallel capacitance C₀ max. 7 pF Resonance resistance R₁ max. 50 Ω

Frequency tolerance in different temperature ranges

with respect to + 25 °C see Table

Maximum permissible d.c. voltage between terminations

between terminations 100 V

Aging after 90 days non-operative at $+85 \pm 2$ °C (-0,5 to + 1) \times 10⁻⁶

TESTS

Mechanical and climatic tests according to MIL and IEC procedures.

temperature	frequency tolerance		
oC range	class 0	class I	class II
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 13 × 10 ⁻⁶ ± 30 × 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶
T _{nom} ± 5		± 2,5 × 10 ⁻⁶	± 5 x 10 ⁻⁶



QUICK REFERENCE DATA

Frequency range	50 to 125 MHz
Mode of vibration	fifth overtone
Type of holder	HC-26/U or HC-29/U

 $\pm 10 \times 10^{-6}$

 $(-0.5 \text{ to} + 1) \times 10^{-6}$

MECHANICAL DATA

Outlines See general section (A) "Holders"

Mass 0,8 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C

Level of drive	0,5 mW
Motional capacitance C ₁	typ. 0,5 fF
Parallel capacitance C ₀	max. 7 pF
Resonance resistance R ₁ 50 to 90 MHz 90 to 125 MHz	max. 50 Ω max. 70 Ω
Frequency tolerance in different temperature ranges with respect to + 25 °C	see Table
Maximum permissible d.c. voltage between terminations	100 V
Aging after 90 days non-operative	

TESTS

at + 85 ± 2 °C

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature	frequency tolerance			
oC range	class 0	class I	class II	
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶	
T _{nom} ± 5		± 2,5 x 10 ⁻⁶	± 5 × 10 ⁻⁶	

QUICK REFERENCE DATA

50 to 125 MHz Frequency range Mode of vibration fifth overtone Type of holder RW-43 or RW-42

MECHANICAL DATA

Outlines

See general section (A) "Holders".

Mass

ELECTRICAL DATA

Adjustment tolerance at + 25 °C $\pm 20 \times 10^{-6}$ Level of drive 0.5 mW Motional capacitance C₁ typ. 0,5 fF Parallel capacitance Co. max. 7 pF

Resonance resistance R₁

50 to 90 MHz max. 60Ω 90 to 125 MHz max. 80Ω

Frequency tolerance in different temperature ranges with respect to + 25 °C

Maximum permissible d.c. voltage

between terminations

Aging

100 V

see Table

within adjustment tolerance

TESTS

Mechanical and climatic tests according to MIL and IEC procedures.

temperature	frequency tolerance			
oC range	class 0	class I	class II	
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 × 10 ⁻⁶ ± 7,5 × 10 ⁻⁶ ± 10 × 10 ⁻⁶ ± 25 × 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 x 10 ⁻⁶ ± 15 x 10 ⁻⁶ ± 20 x 10 ⁻⁶ ± 40 x 10 ⁻⁶	
T _{nom} ± 5		± 5 x 10 ⁻⁶		

QUICK REFERENCE DATA

Frequency range	50 to 125 MHz
Mode of vibration	fifth overtone
Type of holder	RW-36

MECHANICAL DATA

Outlines See general section (A) "Holders".

Mass 4 g

ELECTRICAL DATA

Adjustment tolerance at + 25 °C \pm 20 x 10⁻⁶ Level of drive 0,5 mW Motional capacitance C₁ typ. 0,5 fF Parallel capacitance C₀ max. 7 pF Resonance resistance R₁ 20 to 100 Ω

Frequency tolerance in different temperature ranges

with respect to + 25 °C see Table

Maximum permissible d.c. voltage

between terminations 100 V

Aging

within the adjustment tolerance

TESTS

Table Frequency tolerance in different temperature ranges with respect to + 25 °C

temperature range	frequency tolerance			
oC .	class 0	class i	class II	
-5/+ 50 -10/+ 60 -20/+ 70 -55/+ 105	± 5 x 10 ⁻⁶ ± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 25 x 10 ⁻⁶	± 7,5 x 10 ⁻⁶ ± 10 x 10 ⁻⁶ ± 13 x 10 ⁻⁶ ± 30 x 10 ⁻⁶	± 10 × 10 ⁻⁶ ± 15 × 10 ⁻⁶ ± 20 × 10 ⁻⁶ ± 40 × 10 ⁻⁶	
T _{nom} ± 5		± 5 x 10 ⁻⁶		

TEMPERATURE COMPENSATED CRYSTAL OSCILLATORS

D

		7.1)
	L (_	- -
	ב	Y X Y)

frequency range MHz	temperature range oC	frequency tolerance x 10 ⁻⁶	supply voltage 12 V \pm %	adjustable with external trimmer	basic catalogue number
4,5 to 15	0 to + 50 10 to + 60	1 + 1 + 5	20	OU	4322 190
	-20 to +70	±2	20		
4,5 to 15	0 to + 50	+ 1	20	yes	4322 191
	-10 to +60	+ 1,5	20		
	-20 to + 70	± 2	20		
20 to 50	0 to + 50	+1	2	yes	4322 195
	-20 to + 70	±2	2		
	0 to + 50	+2	. 01		
	-20 to +70	° +1	10		

TEMPERATURE COMPENSATED CRYSTAL OSCILLATOR

QUICK REFERENCE DATA

Frequency range	4,5 - 15 MHz *
Frequency tolerance	
0 to + 50 °C	$\pm 1 \times 10^{-6}$
-10 to + 60 °C	± 1,5 × 10 ⁻⁶
-20 to + 70 °C	± 2 × 10 ⁻⁶
Aging	\pm 1 x 10 ⁻⁶ per year
Correction on aging (fixed step)	typ. -2×10^{-6}

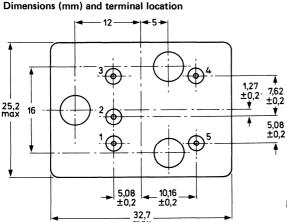
APPLICATION

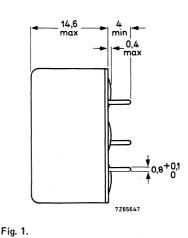
Temperature compensated crystal oscillators (TCXOs) are used in mobilophones, electronic timing devices, measuring equipment, synthesizers, etc.

DESCRIPTION

A TCXO module comprises a quartz crystal oscillator, and a thermally controlled circuit that compensates for frequency changes over the whole temperature range. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with 5 connecting pins which are arranged to fit printed-wiring boards with a grid pitch of 2,54 mm (see Fig. 1).

MECHANICAL DATA





- A 5 MHz TCXO can be ordered under catalogue number 4322 190 00010; an 8 MHz TCXO can be ordered under catalogue number 4322 190 00020;
- a 10 MHz TCXO can be ordered under catalogue number 4322 190 00000.

TCXOs with other frequencies can be ordered under number 4322 190 stating the required frequency.

Mass

25 g approximately

Marking

The units are provided with a label showing the following information:

тсхо	Type 4322 190
Frequency Δf 25 °C Range No.	MHz Hz °C

ELECTRICAL DATA

Supply voltage, V_S $+ 12 \text{ V} \pm 10\% \text{ via R}_1 = 470 \ \Omega \text{ (see Fig. 2)}$ $+ 12 \text{ V} \pm 20\% \text{ via R}_1 = 330 \ \Omega$

Power consumption max. 200 mW Frequency range 4,5 - 15 MHz

-20 to +70 °C ± 1,5 x 10 ± 2 x 10-6

Aging $\pm 1 \times 10^{-6}$ per year

Correction on aging influence by connecting pin 3 to pin 2 $-2 + 1 \\ -0.5 \times 10^{-6}$

 $\begin{array}{ll} \text{Internal resistance, R}_{i} & 2800 \ \Omega \pm 5\% \\ \\ \text{Internal capacitance, C}_{i} & 5,5 \ \text{pF} \pm 5\% \\ \end{array}$

Internal voltage source, V $_{1}$ 600 mV \pm 40% Load impedance, Z $_{1}$ min. 500 Ω

Output voltage, V_O see Figs 3 and 4

Storage temperature range —40 to +85 °C

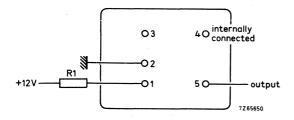


Fig. 2 Connection diagram.

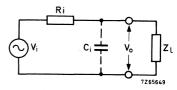


Fig. 3 Equivalent circuit.

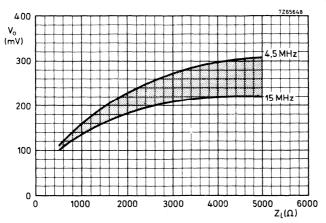


Fig. 4 Output voltage as a function of load impedance (typical values).

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f \text{ max. 5 x } 10^{-7}$
F'	vibration	10 to 500 Hz, 10g, in 3 directions, 30 min per direction	$\Delta f/f$ max. 5 x 10^{-7}
Т	soldering		
D	climatic		Δ f/f max. 5 x 10 ⁻⁷

Note

Other specifications for TCXOs with respect to temperature range and for frequency tolerance can be made available on request.



TEMPERATURE COMPENSATED CRYSTAL OSCILLATOR

QUICK REFERENCE DATA

Frequency range	4,5 to 15 MHz *
Frequency tolerances	
0 to + 50 °C	± 1 x 10 ⁻⁶
-10 to + 60 °C	$\pm 1.5 \times 10^{-6}$
-20 to + 70 °C	$\pm 2 \times 10^{-6}$
Aging	± 1 x 10 ⁻⁶ per year
Frequency adjustable with external trimmer	

APPLICATION

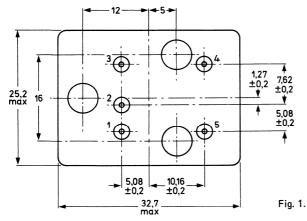
Temperature compensated crystal oscillators (TCXOs) are used in mobilophones, electronic timing devices, measuring equipment, synthesizers, etc.

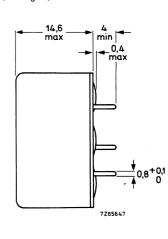
DESCRIPTION

A TCXO module comprises a quartz crystal oscillator, and a thermally controlled circuit that compensates for frequency changes over the whole temperature range. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with 5 connecting pins which are arranged to fit printed-wiring boards with a grid pitch of 2,54 mm (see Fig. 1).

MECHANICAL DATA

Dimensions (mm) and terminal location





- * A 5 MHz TCXO can be ordered under catalogue number 4322 191 00011;
 - an 8 MHz TCXO can be ordered under catalogue number 4322 191 00021;
 - a 10 MHz TCXO can be ordered under catalogue number 4322 191 00001.

TCXOs with other frequencies can be ordered under number 4322 191 stating the required frequency.

Mass

25 g approximately

Marking

The units are provided with a label showing the following information:

тсхо	Type 4322 191
Frequency Δf 25 ^O C Range No.	MHz Hz °C

ELECTRICAL DATA

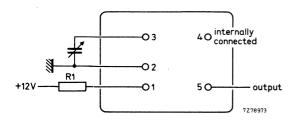
Supply voltage, V_s + 12 V \pm 10% via R₁ = 470 Ω (see Fig. 2) + 12 V \pm 20% via R₁ = 330 Ω Power consumption max. 200 mW Frequency range 4,5 - 15 MHz Frequency tolerance after adjustment (see note), at specified V_S, Z_L, and at a temperature rate of max. 1 oC/min 0 to + 50 °C $\pm 1 \times 10^{-6}$ ± 1.5 x 10⁻⁶ $-10 \text{ to} + 60 \, ^{\circ}\text{C}$ $\pm 2 \times 10^{-6}$ $-20 \text{ to} + 70 \, ^{\circ}\text{C}$ Aging \pm 1 x 10⁻⁶ per year ± 2 x 10⁻⁶ (see note below) Correction on aging influence 2800 Ω ± 5% Internal resistance, Ri $5.5 pF \pm 5\%$ Internal capacitance, Ci Internal voltage source, Vi 600 mV ± 40% min. 500 Ω Load impedance, Z₁ see Figs 3 and 4 Output voltage, Vo.

 $-40 \text{ to} + 85 ^{\circ}\text{C}$

Note

It is not guaranteed that the nominal frequency occurs at room temperature. The nominal frequency can be shifted by connecting a variable capacitor of max. 60 pF externally between pin 2 and 3. For optimum stability over the whole temperature range the oscillator should be adjusted at room temperature to a frequency which deviates from the nominal one by an amount mentioned as " Δf 25 °C ... Hz" on the label on the module. After this adjustment a trimming range of \pm min. 2 x 10^{-6} is still available to correct aging influences.

Storage temperature range



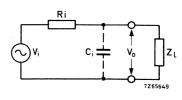


Fig. 2 Connection diagram.

Fig. 3 Equivalent circuit.

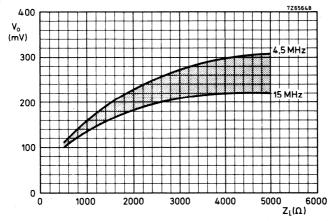


Fig. 4 Output voltage as a function of load impedance (typical values).

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f \text{ max. 5 x } 10^{-7}$
F .	vibration	10 to 500 Hz, 10g, in 3 directions 30 min per direction	$\Delta f/f$ max. 5 x 10 ⁻⁷
Т	soldering		
D	climatic		$\Delta f/f \text{ max. } 5 \times 10^{-7}$

Note

Other specifications for TCXOs with respect to temperature range and for frequency tolerance can be made available on request.





TEMPERATURE COMPENSATED CRYSTAL OSCILLATOR

QUICK REFERENCE DATA

Frequency range	20 to 50 MHz	
Supply voltage	12 V ± 2% 12 V ± 10%	
Frequency tolerance $0 \text{ to} + 50 ^{\circ}\text{C}$ $-20 \text{ to} + 70 ^{\circ}\text{C}$	± 1 × 10 ⁻⁶	
Aging	\pm 1 x 10 ⁻⁶ per year	
Frequency is adjustable with external trimmer		

APPLICATION

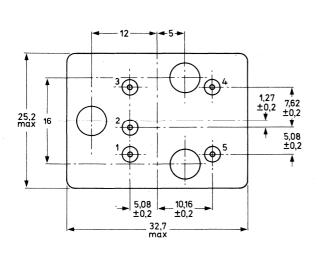
Temperature compensated crystal oscillators (TCXOs) are used in mobilophones, electronic timing devices, measuring equipment, synthesizers, etc.

DESCRIPTION

A TCXO module comprises a quartz crystal oscillator, and a thermally controlled circuit that compensates for frequency changes over the whole temperature range. The metal housing is filled with dry nitrogen and hermetically sealed. The unit is provided with 5 connecting pins which are arranged to fit printed-wiring boards with a grid pitch of 2,54 mm (see Fig. 1).

MECHANICAL DATA

Dimensions (mm) and terminal location



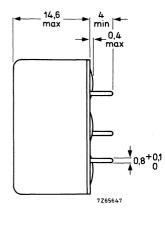


Fig. 1.

Mass

25 g approximately

Marking

The units are provided with a label showing the following information:

тсхо	Type 4322 19 5	
Frequency Δf 25 °C Range No.	MHz Hz °C	

ELECTRICAL DATA

Supply voltage, V_S

Power consumption

Frequency range

Frequency tolerance after adjustment (see note),

at specified V_s, Z_L, and at a temperature rate of 1 °C/min

Aging

Correction on aging influence

Internal resistance, Ri

Internal capacitance, C_i
Internal voltage source, V_i

Load impedance, Z_L

Output voltage, V_0

Storage temperature range

+ 12 V \pm max. 10% via R $_1$ = 390 $\Omega,$ see Fig. 2

typ. 160 mW, max. 180 mW

20 to 50 MHz

see Fig. 4

 \pm 1 x 10⁻⁶ per year

 $\pm > 2 \times 10^{-6}$, see note

2800 Ω ± 5%

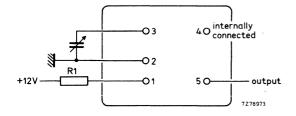
5.5 pF ± 5%

600 mV ± 40%

min. 500 Ω

see Fig. 5

 $-40 \text{ to} + 85 \, ^{\circ}\text{C}$



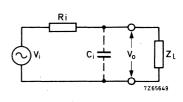


Fig. 2 Connection diagram.

Fig. 3 Equivalent circuit.

Note

It is not guaranteed that the nominal frequency occurs at room temperature. The nominal frequency can be shifted by connecting a variable capacitor of max. 20 pF externally between pins 2 and 3. For optimum stability over the whole temperature range the oscillator should be adjusted at room temperature to a frequency which deviates from the nominal one by an amount mentioned as " Δf 25 °C ... Hz" on the label on the module. After this adjustment a trimming range of \pm min. 2 x 10^{-6} is still available to correct aging influences.

tolerance on V_s (%)

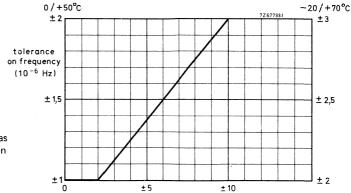


Fig. 4 Frequency tolerance as a function of the tolerance on supply voltage.

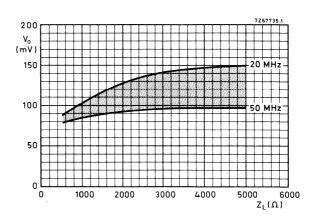


Fig. 5 Output voltage as a function of load impedance (typical values).

ENVIRONMENTAL TESTS AND REQUIREMENTS

IEC 68-2 test method	test	procedure	requirements
Ea	shock	50g, 1 x, in 6 directions	$\Delta f/f \text{ max. 5 x } 10^{-7}$
F	vibration	10 to 500 Hz, 10g, in 3 directions, 30 min per direction	$\Delta f/f$ max. 5 x 10^{-7}
Т	soldering		
D	climatic	and the second s	$\Delta f/f$ max. 5 x 10 ⁻⁷

Note

Other TCXO specifications concerning supply voltage, temperature range and frequency tolerance can be made available on request.

PIEZOELECTRIC QUARTZ DEVICES

- A QUARTZ CRYSTAL UNITS GENERAL
- B QUARTZ CRYSTAL UNITS FOR SPECIAL APPLICATIONS
- C . QUARTZ CRYSTAL UNITS FOR GENERAL FREQUENCY STABILIZATION
- D TEMPERATURE COMPENSATED CRYSTAL OSCILLATORS



Argentina: FAPESA I.y.C., Av. Crovara 2550, Tablada, Prov. de BUENOS AIRES, Tel. 652-7438/7478.

Australia: PHILIPS INDUSTRIES HOLDINGS LTD., Elcoma Division, 67 Mars Road, LANE COVE, 2066, N.S.W., Tel. 427 08 88.

Austria: ÖSTERREICHISCHE PHILIPS BAUELEMENTE Industrie G.m.b.H., Triester Str. 64, A-1101 WIEN, Tel. 62 91 11,

Belgium: M.B.L.E., 80, rue des Deux Gares, B-1070 BRUXELLES, Tel. 523 00 00.

Brazil: IBRAPE, Caixa Postal 7383, Av. Brigadeiro Fari Alima, 1735 SAO PAULO, SP, Tel. (011) 211-2600.

Canada: PHILIPS ELECTRONICS LTD., Electron Devices Div., 601 Milner Ave., SCARBOROUGH, Ontario, M1B 1M8, Tel. 292-5161.

Chile: PHILIPS CHILENA S.A., Av. Santa Maria 0760, SANTIAGO, Tel. 39-40 01.

Colombia: SADAPE S.A., P.O. Box 9805, Calle 13, No. 51 + 39, BOGOTA D.E. 1., Tel. 600 600.

Denmark: MINIWATT A/S, Emdrupvej 115A, DK-2400 KØBENHAVN NV., Tel. (01) 69 16 22.

Finland: OY PHILIPS AB, Elcoma Division, Kaivokatu 8, SF-00100 HELSINKI 10, Tel. 1 72 71.

France: R.T.C. LA RADIOTECHNIQUE-COMPELEC, 130 Avenue Ledru Rollin, F-75540 PARIS 11, Tel. 355-44-99.

Germany: VALVO, UB Bauelemente der Philips G.m.b.H., Valvo Haus, Burchardstrasse 19, D-2 HAMBURG 1, Tel. (040) 3296-1.

Greece: PHILIPS S.A. HELLENIQUE, Elcoma Division, 52, Av. Syngrou, ATHENS, Tel. 915 311.

Hong Kong: PHILIPS HONG KONG LTD., Elcoma Div., 15/F Philips Ind. Bldg., 24-28 Kung Yip St., KWAI CHUNG, Tel. NT 24 51 21.

India: PHILIPS INDIA LTD., Elcoma Div., Band Box House, 254-D, Dr. Annie Besant Rd., Prabhadevi, BOMBAY-25-DD, Tel. 457 311-5.

Indonesia: P.T. PHILIPS-RALIN ELECTRONICS, Elcoma Division, 'Timah' Building, Jl. Jen. Gatot Subroto, P.O. Box 220, JAKARTA, Tel. 44163.

Ireland: PHILIPS ELECTRICAL (IRELAND) LTD., Newstead, Clonskeagh, DUBLIN 14, Tel. 69 33 55.

Italy: PHILIPS S.p.A., Sezione Elcoma, Piazza IV Novembre 3, I-20124 MILANO, Tel. 2-6994.

Japan: NIHON PHILIPS CORP., Shuwa Shinagawa Bidg., 26-33 Takanawa 3-chome, Minato-ku, TOKYO (108), Tel. 448-5611. (IC Products) SIGNETICS JAPAN, LTD., TOKYO, Tel. (03) 230-1521.

Korea: PHILIPS ELECTRONICS (KOREA) LTD., Elcoma Div., Philips House, 260-199 Itaewon-dong, Yongsan-ku, C.P.O. Box 3680, SEOUL, Tel. 794-4202.

Malaysia: PHILIPS MALAYSIA SDN. BERHAD, Lot 2, Jalan 222, Section 14, Petaling Jaya, P.O.B. 2163, KUALA LUMPUR, Selangor, Tel. 77 44 11.

Mexico: ELECTRONICA S.A. de C.V., Varsovia No. 36, MEXICO 6, D.F., Tel. 533-11-80.

Netherlands: PHILIPS NEDERLAND B.V., Afd. Elonco, Boschdijk 525, 5600 PD EINDHOVEN, Tel. (040) 79 33 33.

New Zealand: PHILIPS ELECTRICAL IND. LTD., Elcoma Division, 2 Wagener Place, St. Lukes, AUCKLAND, Tel. 867 119.

 $\textbf{Norway:} \ \text{NORSK A/S PHILIPS, Electronica, Sorkedals veien 6, OSLO 3, Tel. 46\,38\,90.}$

Peru: CADESA, Rocca de Vergallo 247, LIMA 17, Tel. 62 85 99.

Philippines: PHILIPS INDUSTRIAL DEV. INC., 2246 Pasong Tamo, P.O. Box 911, Makati Comm. Centre, MAKATI-RIZAL 3116, Tel. 86-89-51 to 59.

Portugal: PHILIPS PORTUGESA S.A.R.L., Av. Eng. Duharte Pacheco 6, LISBOA 1, Tel. 68 31 21.

Singapore: PHILIPS PROJECT DEV. (Singapore) PTE LTD., Elcoma Div., P.O.B. 340, Toa Payoh CPO, Lorong 1, Toa Payoh, SINGAPORE 12, Tel. 53 88 11. South Africa: EDAC (Pty.) Ltd., South Park Lane, New Doornfontein, JOHANNESBURG 2001, Tel. 24/6701.

Spain: COPRESA S.A., Balmes 22, BARCELONA 7, Tel. 301 63 12.

Sweden: A.B. ELCOMA, Lidingövägen 50, S-115 84 STOCKHOLM 27, Tel. 08/67 97 80.

Uruguay: LUZILECTRON S.A., Rondeau 1567, piso 5, MONTEVIDEO, Tel. 9 43 21.

Switzerland: PHILIPS A.G., Elcoma Dept., Allmendstrasse 140-142, CH-8027 ZÜRICH, Tel. 01/43 22 11.

Talwan: PHILIPS TAIWAN LTD., 3rd Fl., San Min Building, 57-1, Chung Shan N. Rd, Section 2, P.O. Box 22978, TAIPEI, Tel. 5513101-5.

Thailand: PHILIPS ELECTRICAL CO. OF THAILAND LTD., 283 Silom Road, P.O. Box 961, BANGKOK, Tel. 233-6330-9.

Turkey: TÜRK PHILIPS TICARET A.S., EMET Department, Inonu Cad. No. 78-80, ISTANBUL, Tel. 43 59 10.
United Kingdom: MULLARD LTD., Mullard House, Torrington Place, LONDON WC1E 7HD, Tel. 01-580 6633.

United States: (Active devices & Materials) AMPEREX SALES CORP., Providence Pike, SLATERSVILLE, R.I. 02876, Tel. (401) 762-9000.

(Passive devices) MEPCO/ELECTRA INC., Columbia Rd., MORRISTOWN, N.J. 07960, Tel. (201) 539-2000.

(IC Products) SIGNETICS CORPORATION, 811 East Arques Avenue, SUNNYVALE, California 94086, Tel. (408) 739-7700.

Venezuela: IND. VENEZOLANAS PHILIPS S.A., Elcoma Dept., A. Ppal de los Ruices, Edif. Centro Colgate, CARACAS, Tel. 36 05 11.

A12 © 1979 N.V. Philips' Gloeilampenfabrieken

This information is furnished for guidance, and with no guarantees as to its accuracy or completeness; its publication conveys no licence under any patent or other right, nor does the publisher assume liability for any consequence of its use; specifications and availability of goods mentioned in it are subject to change without notice; it is not to be reproduced in any way, in whole or in part, without the written consent of the publisher.